

**FEATURES**

- Current Transfer Ratio**  
MCT5210, >70% at  $I_F=3.0$  mA  
MCT5211, >110% at  $I_F=1.0$  mA
- Saturation CTR-MCT5211, >100% at  $I_F=1.6$  mA**
- High Isolation Voltage, 5300 VAC<sub>RMS</sub>**
- Underwriters Lab File #E52744**
- VDE #0884 Available with Option 1**

**DESCRIPTION**

The MCT5210/5211 are optocouplers with a high efficiency AlGaAs LED optically coupled to a NPN phototransistor. The high performance LED makes operation at low input currents practical. The coupler is housed in a double molded, six pin DIP package. Isolation test voltage is 5300 VAC<sub>RMS</sub>.

Because these parts have guaranteed CTRs at one and three mA, they are ideally suitable for interfacing from CMOS to TTL or LSTTL to TTL. They are also ideal for telecommunications applications such as ring or off-hook detection.

**Maximum Ratings****Emitter**

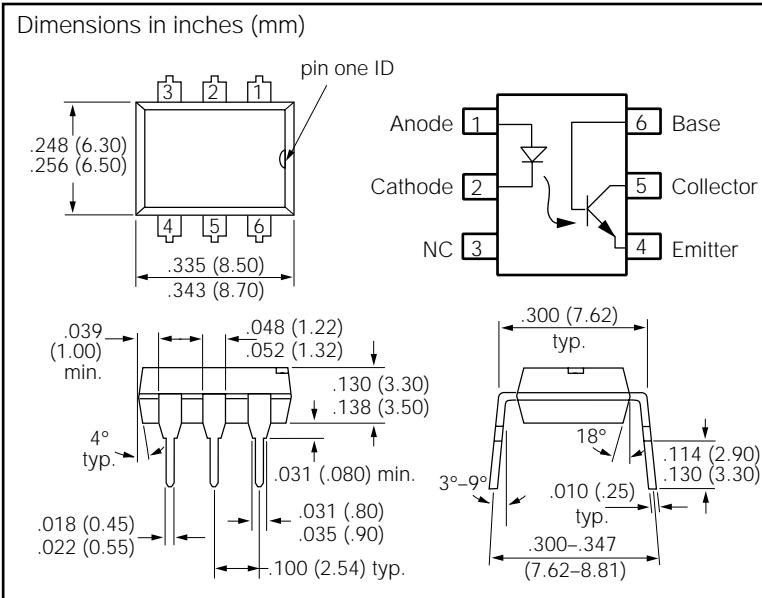
Peak Reverse Voltage .....	6 V
Continuous Forward Current .....	40 mA
Power Dissipation at 25°C.....	75 mW
Derate Linearly from 25°C .....	1.0 mW/°C

**Detector**

Collector-Emitter Breakdown Voltage.....	30 V
Emitter-Collector Breakdown Voltage.....	7 V
Collector-Base Breakdown Voltage.....	70 V
Power Dissipation.....	200 mW
Derate Linearly from 25°C .....	2.6 mW/°C

**Package**

Isolation Test Voltage.....	5300 VAC <sub>RMS</sub>
Total Package Dissipation	
at 25°C Ambient (LED + Detector) .....	260 mW
Derate Linearly from 25°C .....	3.5 mW/°C
Leakage Path .....	7 mm min.
Clearance Path.....	7 mm min.
Comparative Tracking Index per	
DIN IEC 112/VDE 0303, part 1 .....	175
Isolation Resistance	
$V_{IO}=500$ V, $T_A=25^\circ\text{C}$ .....	$\geq 10^{12} \Omega$
$V_{IO}=500$ V, $T_A=100^\circ\text{C}$ .....	$\geq 10^{11} \Omega$
Operating Temperature .....	-55°C to +100°C
Storage Temperature.....	-55°C to +150°C

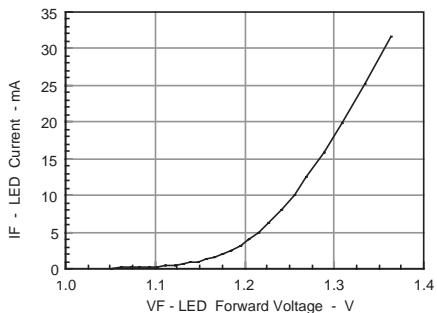
**Electrical Characteristics (25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Emitter						
Forward Voltage	$V_F$		1.2	1.5	V	$I_F=5$ mA
Reverse Voltage	$V_R$	6			V	$I_R=10$ $\mu$ A
Detector						
	HFE	100	200			$V_{CE}=5$ V $I_C=100$ $\mu$ A
	$BV_{CEO}$	30			V	$I_C=100$ $\mu$ A
	$BV_{ECO}$	7			V	$I_E=100$ $\mu$ A
	$BV_{CBO}$	70			V	$I_E=10$ $\mu$ A
	$I_{CEO}$		5	100	nA	$V_{CE}=10$ V
Package (0–70°C)						
Saturated Current Transfer Ratio						$V_{CE}=0.4$ V
MCT5210	$CTR_{CESat}$	60	120		%	$I_F=3.0$ mA
MCT5211	$CTR_{CESat}$	100	200		%	$I_F=1.6$ mA
MCT5211	$CTR_{CESat}$	75	150		%	$I_F=1.0$ mA
Current Transfer Ratio						$V_{CE}=5.0$ V
MCT5210	$CTR$	70	150		%	$I_F=3.0$ mA
MCT5211	$CTR$	150	300		%	$I_F=1.6$ mA
MCT5211	$CTR$	110	225		%	$I_F=1.0$ mA
Collector-Base Current Transfer Ratio						$V_{CE}=4.3$ V
MCT5210	$CTR_{CB}$	0.2	0.4		%	$I_F=3.0$ mA
MCT5211	$CTR_{CB}$	0.3	0.6		%	$I_F=1.6$ mA
MCT5211	$CTR_{CB}$	0.25	0.5		%	$I_F=1.0$ mA
Saturation Voltage						
MCT5210	$V_{CESat}$		0.25	0.4	V	$I_F=3.0$ mA $I_C=1.8$ mA
MCT5211	$V_{CESat}$		0.25	0.4	V	$I_F=1.6$ mA $I_C=1.6$ mA

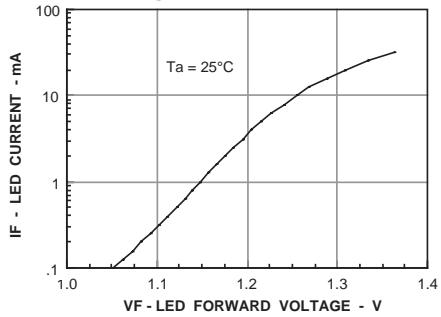
## Characteristics — continued

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
<b>Switching Characteristics (25°C)</b>						
Propagation Delay — High to Low						
MCT5210	tPHL		10		μs	$R_L = 330 \Omega$ , $I_F = 3.0 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$
MCT5211	tPHL		20		μs	$R_L = 750 \Omega$ , $I_F = 1.6 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$
MCT5211	tPHL		40		μs	$R_L = 1.5 \Omega$ , $I_F = 1.0 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$
Propagation Delay — Low to High						
MCT5210	tPLH		10		μs	$R_L = 330 \Omega$ , $I_F = 3.0 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$
MCT5211	tPLH		20		μs	$R_L = 750 \Omega$ , $I_F = 1.6 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$
MCT5211	tPLH		40		μs	$R_L = 1.5 \Omega$ , $I_F = 1.0 \text{ mA}$ , $V_{CC} = 5.0 \text{ V}$

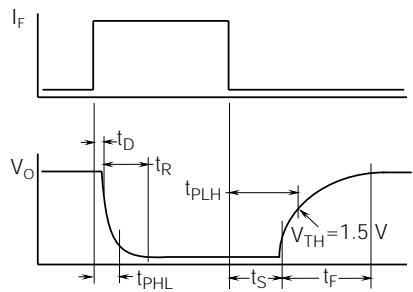
**Figure 1. Forward current vs. forward voltage**



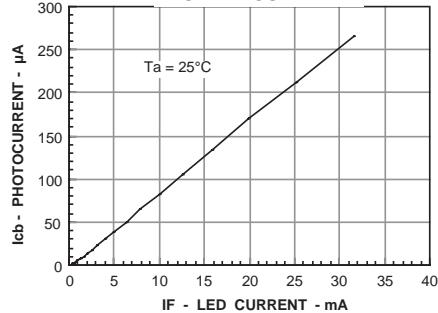
**Figure 2. LED forward current vs. forward voltage**



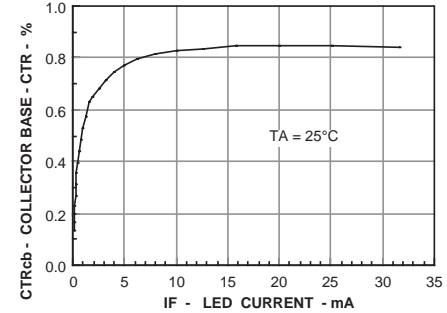
**Figure 3. Switching waveform**



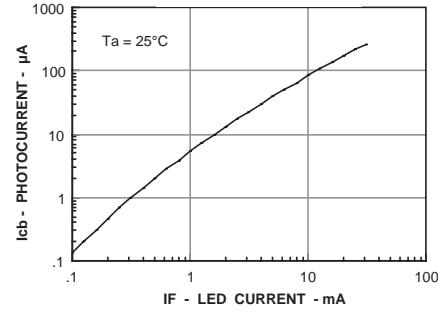
**Figure 4. Collector base photocurrent vs. LED current**



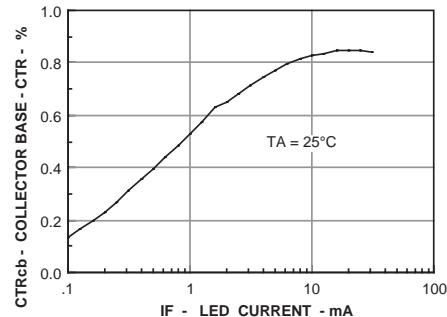
**Figure 7. Collector base current transfer ratio vs. LED current**



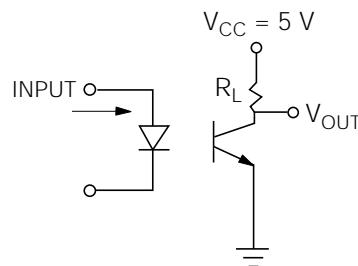
**Figure 5. Photocurrent vs. LED current**



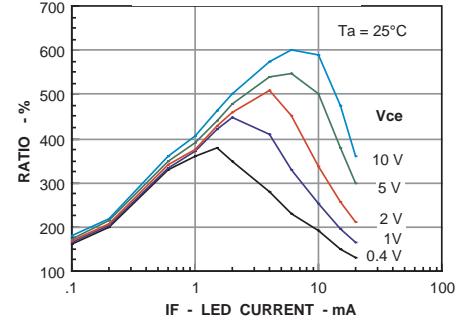
**Figure 8. Collector base current transfer ratio vs. LED current**



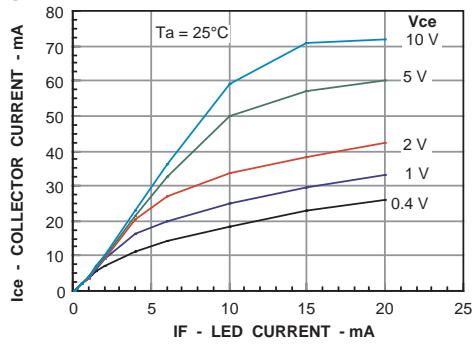
**Figure 6. Switching schematic**



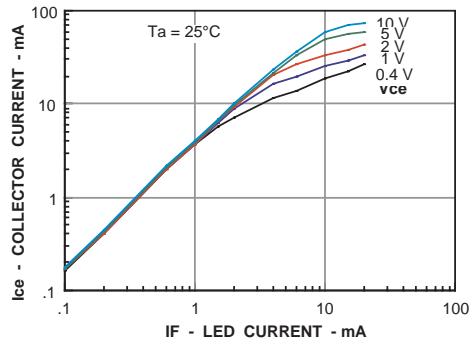
**Figure 9. Current transfer ratio ratio vs. LED current**



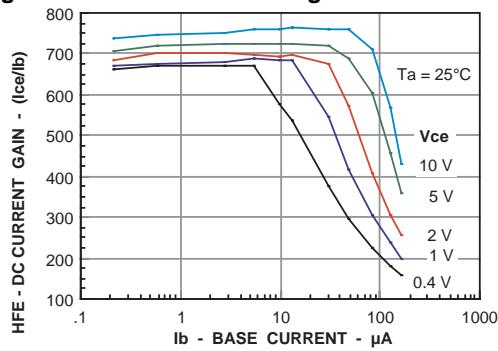
**Figure 10. Collector current vs. LED current**



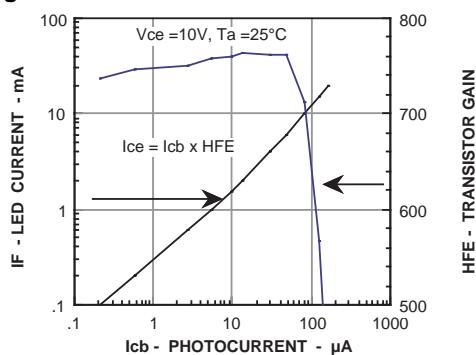
**Figure 11. Collector current vs. LED current**



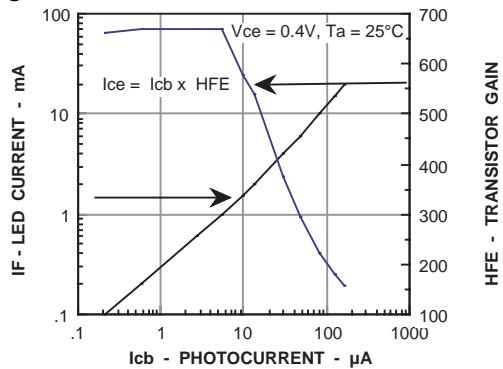
**Figure 12. Transistor current gain vs. base current**



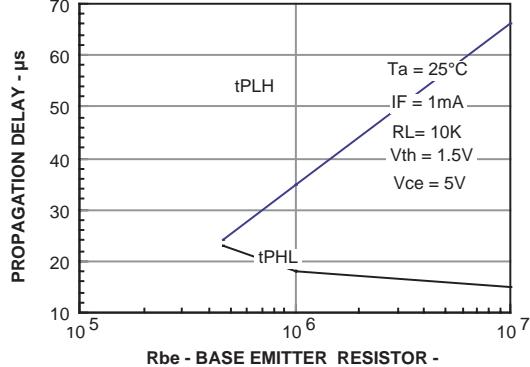
**Figure 13. Transfer curve**



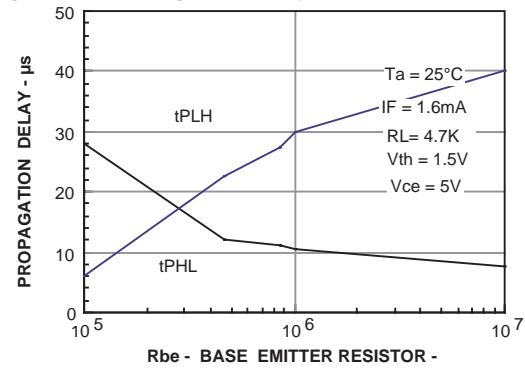
**Figure 14. Transfer curve**



**Figure 15. Propagation delay vs. base emitter resistor**



**Figure 16. Propagation delay vs. base emitter resistor**



**Figure 17. Propagation delay vs. base emitter resistor**

